# NSN 5962-00-137-5012

Memory Microcircuit - Page 1 of 1



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# Body Length:

0.390 inches

## **Body Width:**

0.390 inches

# **Body Height:**

0.070 inches

#### **Maximum Power Dissipation Rating:**

307.2 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and monolithic and positive outputs and bipolar and negative outputs and unipolar and programmable and programmed

#### and w/enable and wire-or outputs

**Inclosure Material:** 

Ceramic and glass

### Inclosure Configuration:

Flat pack

#### **Output Logic Form:**

P-type metal oxide-semiconductor logic

## Input Circuit Pattern:

12 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-20.0 volts power source and 8.3 volts power source

## **Time Rating Per Chacteristic:**

900.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Rom

#### **Test Data Document:**

09128-d34005544 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

30 flat leads

Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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